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Our Case No. 10125-4105

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE 4.25.02

In re Application of:

Chae Gee Sung

Serial No. 09/413,653

Filing Date: October 6, 1999

For Thin Film Transistor, Method of Producing

Thin Film Transistor, Method of Producing the Same, Liquid Crystal Display, and Thin

Film Forming Apparatus

## PRELIMINARY AMENDMENT

Commissioner for Patents Washington, D.C. 20231

Dear Sir:

Prior to examination of the above-identified application, please amend the application as follows:

## In the Specification

On page 1, before first paragraph please insert:

(New) This application is a divisional application of U.S. Application Serial 09/413,653 filed on October 6, 1999, entitled "Thin Film Transistor, Method of Producing the Same, Liquid Crystal Display, and thin Film Forming Apparatus".

Please rewrite the paragraph on page 1, lines 13-23 as follows:

(Amended) Fig. 14 relates to a conventional ordinary liquid crystal display using thin film transistors (hereinafter referred to as TFTs), and illustrates one example of the structure of a TFT array board including TFTs of the reverse stagger type, gate lines, source lines, etc. In such a TFT array board, as shown in Fig. 14, gate lines 50 and source lines 51 are arranged on a transparent substrate in a matrix pattern. Each of areas surrounded by the gate lines 50 and the source lines 51

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